

Oral presentation | Joint Session K "Wide bandgap oxide semiconductor materials and devices" | 21.1 Joint Session K "Wide bandgap oxide semiconductor materials and devices"

## [13p-D419-1~16]21.1 Joint Session K "Wide bandgap oxide semiconductor materials and devices"

Takashi Yasuda(Ishinomaki Senshu Univ.), Takumi Ikenoue(Kyoto Univ.)

Fri. Mar 13, 2020 1:45 PM - 6:15 PM D419 (11-419)

△ : Presentation by Applicant for JSAP Young Scientists Presentation Award

▲ : English Presentation

▼ : Both of Above

No Mark : None of Above

---

1:45 PM - 2:15 PM

### [13p-D419-1][The 10th Compound Semiconductor Electronics Achievement Award Speech] Growth of GaAs-based, ZnSe-based, and oxide semiconductors with evolutionary technologies

○Shizuo Fujita<sup>1</sup> (1.Kyoto Univ.)

Keywords:Isamu Akasaki Award